

SCHOTTKY BARRIER DIODE

Features

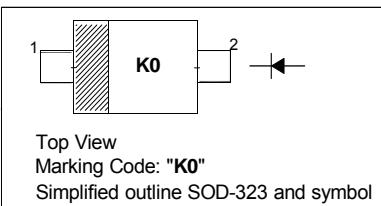
- Medium current schottky rectifier diode

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

Applications

- For low-loss, fast-recovery, meter protection, bias isolation and clamping applications

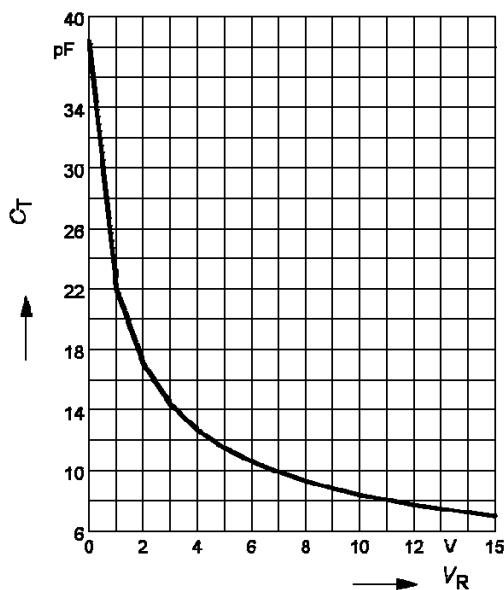
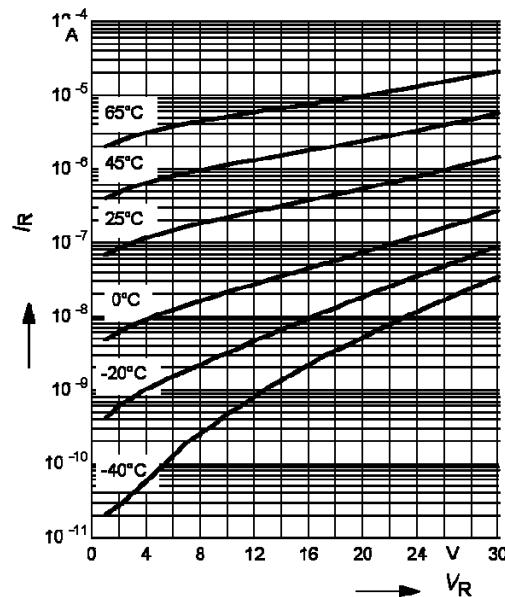
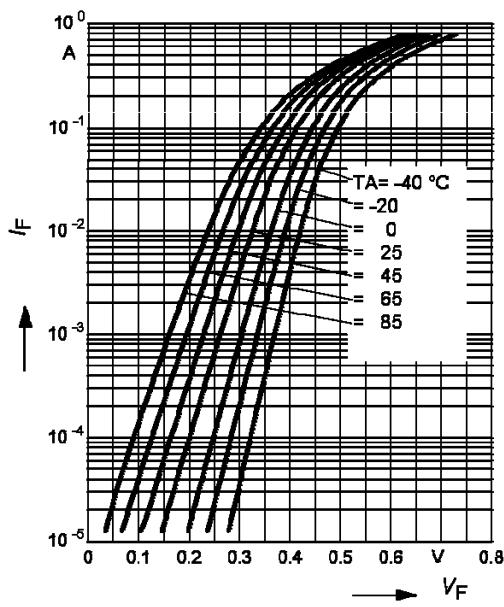
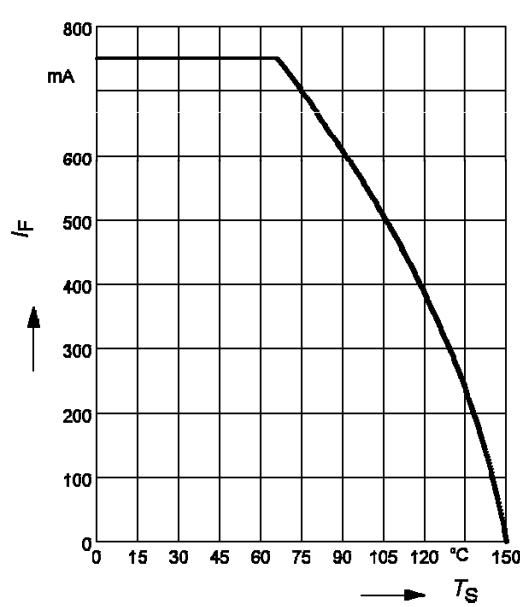


Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	40	V
Average forward current	I_{FAV}	500	mA
Forward Current	I_F	750	mA
Surge Forward Current ($t \leq 10 \text{ ms}$)	I_{FSM}	2.5	A
Total Power Dissipation	P_{tot}	600	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

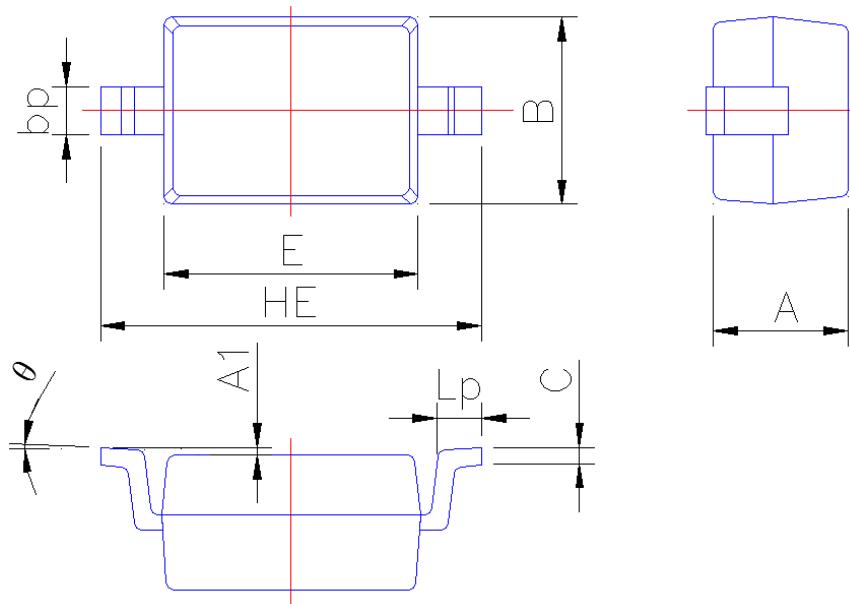
Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 10 \text{ mA}$ at $I_F = 250 \text{ mA}$	V_F	0.4 0.7	V
Reverse Current at $V_R = 30 \text{ V}$ at $V_R = 30 \text{ V}, T_a = 65^\circ\text{C}$	I_R	50 900	μA
Diode Capacitance at $V_R = 10 \text{ V}, f = 1 \text{ MHz}$	C_T	12	pF

Diode capacitance $C_T = f(V_R)$
 $f = 1\text{MHz}$

Reverse current $I_R = f(V_R)$
 $T_A = \text{Parameter}$

Forward current $I_F = f(V_F)$
 $T_A = \text{Parameter}$

Forward current $I_F = f(T_S)$


PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



Symbol	Dimension in Millimeters	
	Min	Max
A	0.95	1.15
A1	0.010	0.100
B	1.20	1.40
bp	0.25	0.40
C	0.09	0.150
E	1.60	1.80
HE	2.30	2.70
Lp	0.20	0.40
θ	0°	5°